

KSC2752

High Speed
High Voltage Switching Industrial Use

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	500	V
V_{CEO}	Collector-Emitter Voltage	400	V
V_{EBO}	Emitter-Base Voltage	7	V
I_C	Collector Current (DC)	0.5	A
I_{CP}	*Collector Current (Pulse)	1	A
I_B	Base Current (DC)	0.25	A
P_C	Collector Dissipation ($T_a=25^\circ\text{C}$)	1	W
P_C	Collector Dissipation ($T_C=25^\circ\text{C}$)	10	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	- 55 ~ 150	$^\circ\text{C}$

* $PW \leq 300\mu\text{s}$, Duty Cycle $\leq 10\%$

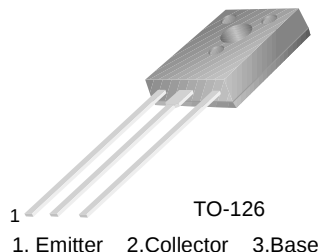
Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
$V_{CE0(sus)}$	Collector-Emitter Sustaining Voltage	$I_C = 0.3\text{A}$, $I_{B1} = 0.06\text{A}$, $L = 10\text{mH}$	400		V
$V_{CEX(sus)1}$	Collector-Emitter Sustaining Voltage	$I_C = 0.3\text{A}$, $I_{B1} = -I_{B2} = 0.06\text{A}$ $V_{BE(off)} = -5\text{V}$, $L = 10\text{mH}$, Clamped	450		V
$V_{CEX(sus)2}$	Collector-Emitter Sustaining Voltage	$I_C = 0.6\text{A}$, $I_{B1} = 0.2\text{A}$, $I_{B2} = -0.06\text{A}$ $V_{BE(off)} = -5\text{V}$, $L = 10\text{mH}$, Clamped	400		V
I_{CBO}	Collector Cut-off Current	$V_{CB} = 400\text{V}$, $I_E = 0$		10	μA
I_{CER}	Collector Cut-off Current	$V_{CE} = 400\text{V}$, $R_{BE} = 51\Omega$, $T_C = 125^\circ\text{C}$		1	mA
I_{CEX1}	Collector Cut-off Current	$V_{CE} = 400\text{V}$, $R_{BE(off)} = -1.5\text{V}$		10	μA
I_{CEX2}	Collector Cut-off Current	$V_{CE} = 400\text{V}$, $R_{BE(off)} = -1.5\text{V}$ @ $T_C = 125^\circ\text{C}$		1	mA
I_{EBO}	Emitter Cut-off Current	$V_{EB} = 5\text{V}$, $I_C = 0$		10	μA
h_{FE1} h_{FE2}	* DC Current Gain	$V_{CE} = 5\text{V}$, $I_C = 0.05\text{A}$ $V_{CE} = 5\text{V}$, $I_C = 0.3\text{A}$	20 10	80	
$V_{CE(sat)}$	* Collector-Emitter Saturation Voltage	$I_C = 0.3\text{A}$, $I_B = 0.06\text{A}$		1	V
$V_{BE(sat)}$	* Base-Emitter Saturation Voltage	$I_C = 0.3\text{A}$, $I_B = 0.06\text{A}$		2	V
t_{ON}	Turn ON Time	$V_{CC} = 150\text{V}$, $I_C = 0.3\text{A}$ $I_{B1} = -I_{B2} = 0.06\text{A}$, $R_L = 500\Omega$ $PW = 50\mu\text{s}$, Duty Cycle $\leq 2\%$		1	μs
t_{STG}	Storage Time			2.5	μs
t_F	Fall Time			1	μs

* Pulse Test: $PW \leq 350\mu\text{s}$, Duty Cycle $\leq 2\%$ Pulsed

h_{FE} Classification

Classification	R	O	Y
h_{FE1}	20 ~ 40	30 ~ 60	40 ~ 80



Typical Characteristics

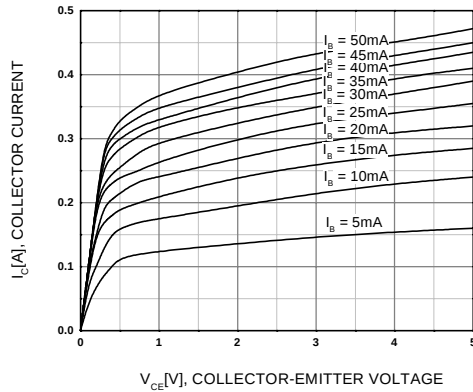


Figure 1. Static Characteristic

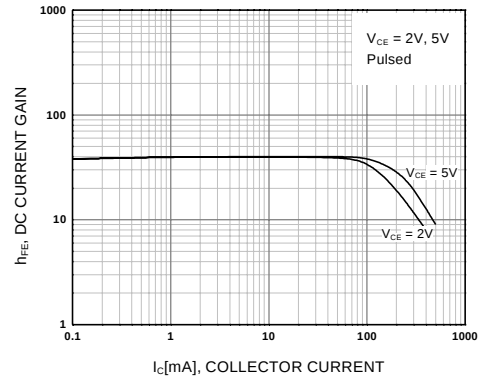


Figure 2. DC current Gain

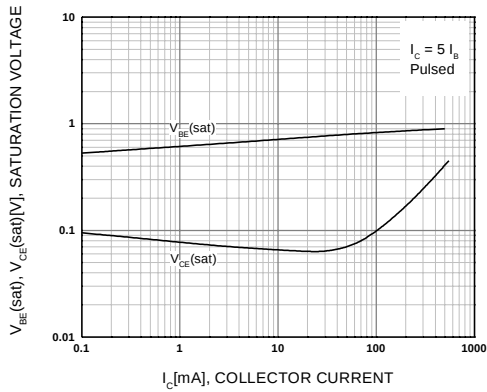


Figure 3. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

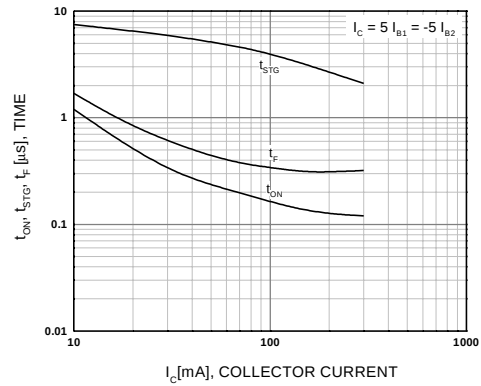


Figure 4. Switching Time

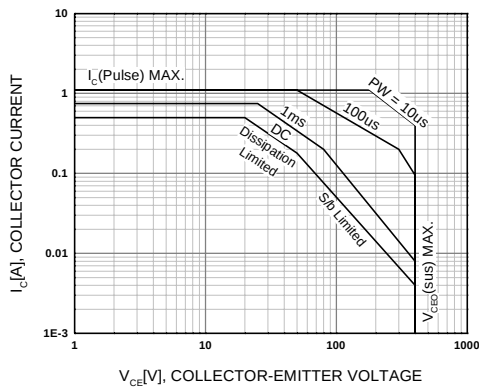


Figure 5. Safe Operating Area

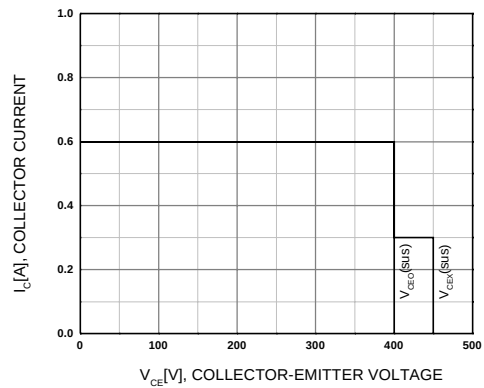


Figure 6. Reverse Bias Safe Operating Area

Typical Characteristics (Continued)

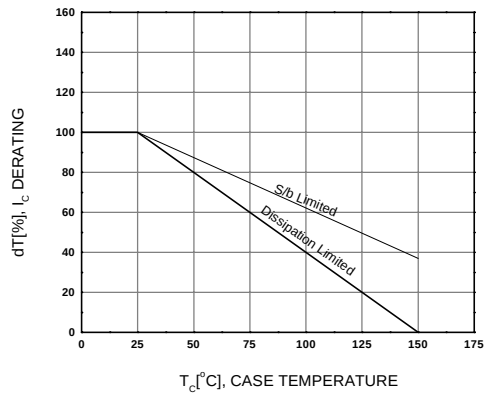


Figure 7. Derating Curve of Safe Operating Area

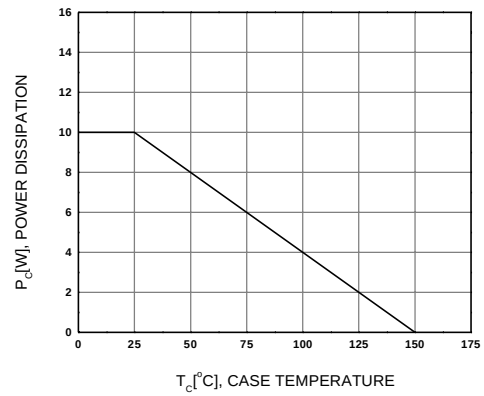


Figure 8. Power Derating

Technical drawing of a 10-pin D-sub connector. The drawing includes a front view, a side view, and a detail of the pin contacts.

Front View Dimensions:

- Overall Width: 8.00 ± 0.30
- Overall Height: 14.20 MAX
- Pin Contact Height: 13.06 ± 0.30
- Pin Contact Spacing: 2.28 TYP [2.28 ± 0.20]
- Pin Contact Width: $0.50^{+0.10}_{-0.05}$
- Pin Contact Height (Detail): 0.75 ± 0.10
- Pin Contact Width (Detail): 0.75 ± 0.10
- Pin Contact Height (Detail): 1.60 ± 0.10
- Pin Contact Width (Detail): 0.75 ± 0.10

Side View Dimensions:

- Overall Height: 11.00 ± 0.20
- Pin Contact Height: 1.75 ± 0.20
- Pin Contact Width: $0.50^{+0.10}_{-0.05}$

Detail Dimensions:

- Pin Contact Width: $0.50^{+0.10}_{-0.05}$
- Pin Contact Height: 0.75 ± 0.10

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